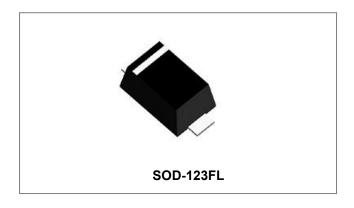






1N4001FL THRU 1N4007FL General Purpose Plastic Rectifier



Features

- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Solder dip 260°C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- "-A" is an AEC-Q101 qualified device
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: SOD-123FL molded plastic
- Terminals: Plated leads solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.0007 ounce, 0.02 grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	1N 4001FL	1N 4002FL	1N 4003FL	1N 4004FL	1N 4005FL	1N 4006FL	1N 4007FL	Units
Marking code		A 1	A2	A3	A 4	A 5	A6	A 7	
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	V _{RRM} V _{DC}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum average forward rectified current @T _L = 100°C	I _(AV)	1.0						Α	
Peak forward surge current 8.3ms single half sine- wave superimposed on rated load (JEDEC Method)	I _{FSM}	30.0				Α			
Maximum instantaneous forward voltage at 1.0A	V _F	1.0				V			
Maximum DC reverse current @T _A = 25°C at rated DC blocking voltage @T _A = 125°C	I _R	5.0 200.0				μΑ			
Typical Junction Capacitance (Note 1)	CJ	6.0			pF				
Typical Thermal Resistance (Note 2)	$R_{ heta JL} \ R_{ heta JA}$	25 123			°C/W				
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150			°C				

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Device mounted on FR-4 substrate, 1"*1", 2oz, single-sided, PC boards with 0.1"*0.15" copper pad.







Ratings and Characteristics Curves

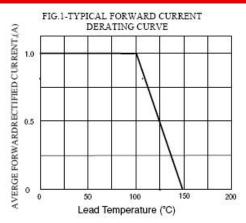


FIG.3-MAXIMUN NON-REPETITIVE FORWARD SURGE CURRENT

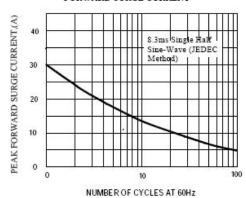


FIG. 5 TYPICAL JUNCTION CAPACITANCE

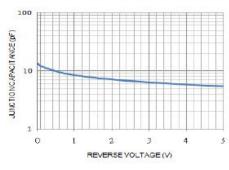
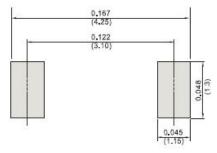


Fig.7 TYPICAL CAPACITANCE



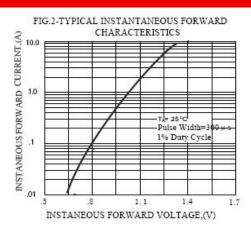


FIG.4-TYPICAL REVERSE CHARACTERISTICS

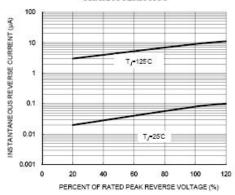
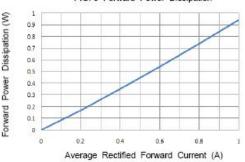


FIG. 6 Forward Power Dissipation



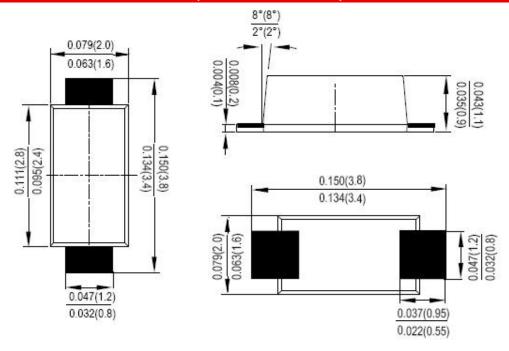
- China Germany Korea Singapore United States
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Mechanical Dimensions SOD-123FL(Inches/Millimeters)

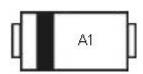


Ordering Information

Device	Package	Shipping			
1N4001FL THRU 1N4007FL	SOD-123FL	3000pcs / reel			
1N4001FLTR THRU 1N4007FLTR	SOD-123FL	3000pcs / reel			

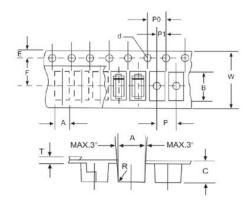
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



1 = Marking Code

Carrier Tape Specification SOD-123FL



SYMBOL	Millimeters			
STWIBOL	Min.	Max.		
Α	1.95	2.15		
В	3.85	4.05		
С	1.35	1.55		
d	1.50	1.60		
Е	1.65	1.85		
F	3.40	3.60		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	7.90	8.30		

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